

3V, 2.5 GHZ LINEAR POWER AMPLIFIER

RF2129

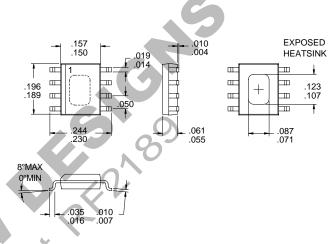
Typical Applications

- 2.5 GHz ISM Band Applications
- PCS Communication Systems
- Wireless LAN Systems

- Commercial and Consumer Systems
- Portable Battery Powered Equipment
- Broadband Spread Spectrum Systems

Product Description

The RF2129 is a linear, medium power, high efficiency amplifier IC designed specifically for low voltage operation. The device is manufactured on an advanced Gallium Arsenide Heterojunction Bipolar Transistor (HBT) process, and has been designed for use as the final RF amplifier in 2.5GHz spread spectrum transmitters. The device is packaged in an 8-lead plastic package with a backside ground and is self-contained with the exception of the output matching network and power supply feed line.



Refer to "Handling of PSOP and PSSOP Products" on page 16-15 for special handling information.

Package Style: PSOP-8

Features

- Single 3.3V Power Supply
- +26dBm Saturated Output Power
- 27dB Small Signal Gain
- High Power Added Efficiency
- Power Down Mode
- 1800MHz to 2500MHz Frequency Range

Ordering Information RF2129 3V, 2.5GHz Linear Power Amplifier RF2129 PCBA Fully Assembled Evaluation Board RF Micro Devices. Inc. Tel (336) 6

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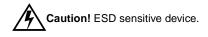
Optimum Technology Matching® Applied GaAs HBT GaAs MESFET Si BJT Si Bi-CMOS SiGe HBT Si CMOS BIAS 8 VCC1 /CC2CIRCUITS 7 RF OUT CC2 6 RF OUT 5 PC PACKAGE BASE GND

Functional Block Diagram

Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage	-0.5 to +6.0	V _{DC}
Power Control Voltage (V _{PC})	-0.5 to 3.3	V
DC Supply Current	350	mA
Input RF Power	+12	dBm
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C
Moisture sensitivity	JEDEC Level 3	

Refer to "Handling of PSOP and PSSOP Products" on page 16-15 for special handling information.



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Demonster	Specification		ا ا ا	Condition	
Parameter	Parameter Min. Typ. Max. Unit	Unit			
Overall					T=25 °C, V _{CC} =3.3V, V _{PC} =3.0V, P _{IN} =0dBm, Freq=2450MHz
Frequency Range		1800 to 2500		MHz	rieq=2430MHz
Maximum Saturated Output Power	+24.5	+26	+27	dBm	P _{IN} =+6dBm
Efficiency at max output power		42		%	
Small Signal Gain	24.5	26.5		dB	
Reverse Isolation		30		dB	In "ON" state
		30		dB	In "OFF" state
Second Harmonic		-50		dBc	Including second harmonic trap, see applica- tion circuit
IM ₃		-30	-23		P _{OUT} =+17dBm in each tone
IM ₅		-35	-30		P _{OUT} =+17dBm in each tone
IM ₇		-48	-35		P _{OUT} =+17dBm in each tone
Isolation	-20	-30		dBm	In "OFF" state, P _{IN} =0dBm
Input Impedance		50		\bigcup_{Ω}	
Input VSWR		2:1			
Noise Figure		7		dB	
Power Down			\mathbf{O}		
Power Control "ON"	2.7		3.0	V	Voltage supplied to control input; device is "ON"
Power Control "OFF"		0	0.5	V	Voltage supplied to control input; device is "OFF"
PC Input Impedance	5	0		kΩ	
Power Supply					
Operating Voltage		3.0 to 5.0		V	
Current Consumption	180	260	320	mA	Power Down "ON", at max output power
	95	150	175	mA	Power Down "ON", two-tone test +20dBm average output power
	50	100	150	mA	Idle current
Current Consumption		<1	10	μA	Power Down "OFF"
See	~				

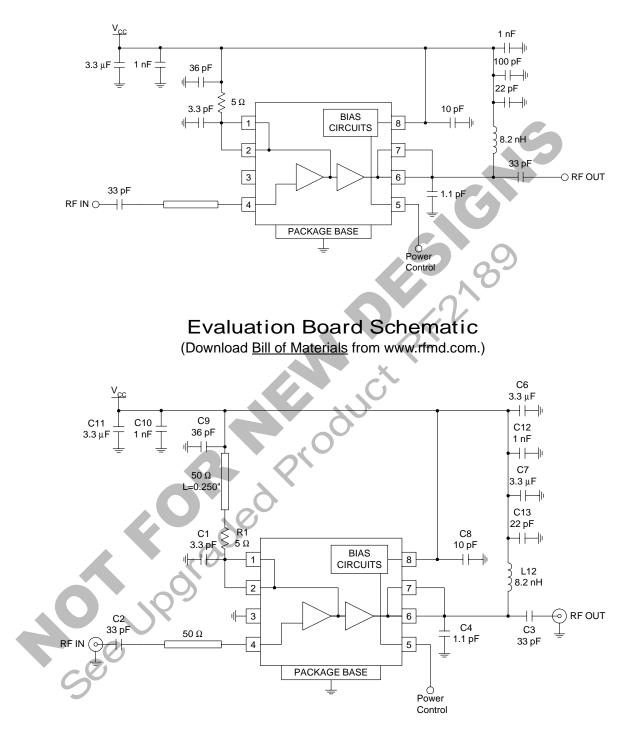
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Pin	Function	Description	Interface Schematic
1	VCC2	Bias supply pin for the first stage. A small tuning capacitor is required to set the desired frequency response. External low frequency bypass capacitors should be connected as shown in the application schematic if no other low frequency decoupling is nearby.	
2	VCC2	Connected internally to pin 1.	See pin 1.
3	NC	Not internally connected.	
4	RF IN	RF input. This input is DC coupled, so an external blocking capacitor is required if this pin is connected to a DC path.	See pin 1.
5	PC	Power control pin. For maximum power this pin should be 3.3V. A higher voltage is not recommended. For less output power and reduced idle current this voltage may be reduced.	VCC1 5000 PC O-W
6	RF OUT	RF output and bias for the output stage. The power supply for the out- put transistor needs to be supplied to this pin. This can be done through a quarter-wave length microstrip line that is RF grounded at the other end, or through an RF inductor that supports the required DC cur- rents.	
7	RF OUT	Same as pin 6.	See pin 6.
8	VCC1	Power supply pin for the bias circuits. External low frequency bypass capacitors should be connected if no other low frequency decoupling is nearby.	See pin 5.
Pkg Base	GND	Ground connection. The backside of the package should be connected to the ground plane through a short path, i.e., vias under the device may be required.	See pin 1 and 6.

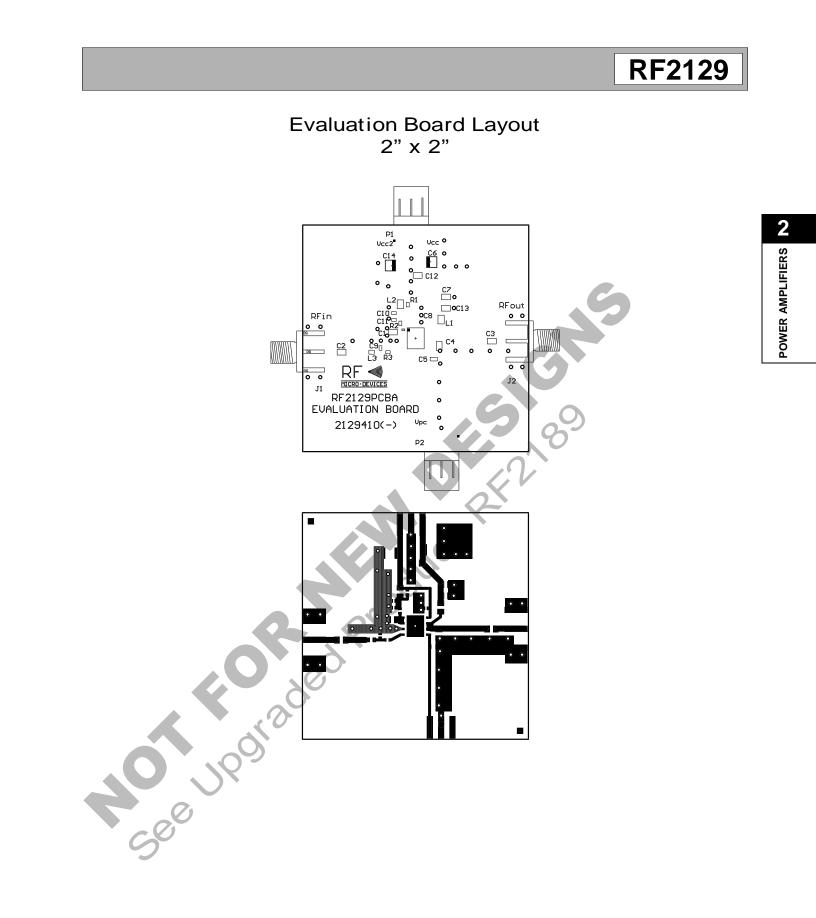
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